

EAST Search History

| Ref # | Hits | Search Query | DBs | Default Operator | Plurals | Time Stamp |
|-------|------|--|---|------------------|---------|------------------|
| L2 | 1 | "6433842".pn. | USPAT | OR | OFF | 2008/04/11 23:59 |
| L3 | 1 | "6081308".pn. | USPAT | OR | OFF | 2008/04/12 00:00 |
| L4 | 46 | ("3893945" "5162933" "5585647" "5614728" "5621556" "5731856" "5739877" "5756372" "5821622" "5844647" "5852481" "5858807").PN. OR ("6081308").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2008/04/12 00:02 |
| L5 | 9 | 257/E21.19 | US-PGPUB; USPAT; USOCR | OR | OFF | 2008/04/12 00:22 |
| L6 | 9 | 257/E21.19 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:23 |
| L7 | 3 | 257/E23.017 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:23 |
| L8 | 20 | 257/E29.137 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:24 |
| L9 | 87 | 257/E29.151 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:24 |

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| L10 | 4393 | 257/59 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:25 |
| L11 | 3853 | 257/72 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:30 |
| L12 | 290 | (semiconductor or die or dice or chip or IC) and gate near wire and gate near line and gate near pad | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/04/12 00:40 |
| L13 | 286 | (semiconductor or die or dice or chip or IC) and gate near wire and gate near line and gate near pad and gate near electrode | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/04/12 00:40 |
| L14 | 178 | (semiconductor or die or dice or chip or IC) and gate near wire and gate near line and gate near pad and gate near electrode and ("Al" or aluminum) with gate near wire | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | ON | 2008/04/12 00:41 |
| L16 | 1583 | 257/763 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:52 |
| L17 | 826 | 257/765 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 00:53 |
| L18 | 1949 | 438/30 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 01:10 |

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| L19 | 2035 | 349/42 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 01:23 |
| L20 | 2127 | 349/139 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 01:39 |
| L21 | 516 | 349/147 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 01:54 |
| L22 | 63 | 257/E27.111 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 01:55 |
| L23 | 2 | "20040140575" | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:00 |
| L24 | 13 | 257/E29.147 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:02 |
| L25 | 3462 | 257/784 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:03 |
| L26 | 480 | 349/46 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:25 |

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| L27 | 4507 | 438/149 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:33 |
| L28 | 3546 | 438/151 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2008/04/12 02:52 |
| S1 | 1 | "6696324".pn. | USPAT | OR | OFF | 2007/12/21 21:21 |
| S2 | 28 | ("5185294" "5289030" "5313090" "5340761" "5403772" "5573959" "5677240" "5734177" "5837619" "5969377" "6017779" "6043512" "6159779" "6218206" "6274412" "6287899" "6338988" "6340610" "6362028" "6395586").PN. OR ("6696324").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/12/21 21:28 |
| S3 | 3 | "5978058".pn. or "6444296".pn. or "5181132".pn. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/12/21 21:30 |
| S4 | 73 | 257/E29.151 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/12/25 17:59 |
| S5 | 82 | 257/E51.005 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/12/25 18:00 |

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| S6 | 3698 | 257/72 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/12/25 18:02 |
| S7 | 1173 | 257/208 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/12/25 18:28 |
| S8 | 819 | 257/765 | US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB | OR | OFF | 2007/12/25 18:28 |
| S9 | 10 | (semiconductor or die or dice or chip or IC) and pad near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat \$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3) | USPAT | OR | ON | 2007/12/25 18:53 |
| S10 | 151 | (semiconductor or die or dice or chip or IC) and (pad or wir\$3) near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat \$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3) | USPAT | OR | ON | 2007/12/25 19:37 |
| S11 | 43 | ("5478766" "5686976" "5844255" "5852488" "6146796" "6156583" "6172733").PN. OR ("6255130").URPN. | US-PGPUB; USPAT; USOCR | OR | OFF | 2007/12/25 19:34 |

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|-----|-----|--|-------|----|----|---------------------|
| S12 | 779 | (semiconductor or die or dice or chip or IC) and (pad or wir\$3 or metal) near ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3) | USPAT | OR | ON | 2007/12/25 20:10 |
| S13 | 628 | S12 not S10 | USPAT | OR | ON | 2007/12/25 20:05 |
| S14 | 1 | "6008065".pn. | USPAT | OR | ON | 2007/12/25 20:06 |
| S15 | 227 | (semiconductor or die or dice or chip or IC) and (pad or wir\$3 or metal) near ("Al" or aluminum) same (cap\$4 or cover\$3 or coat\$3 or plat\$3 or second or upper or top) with ("Al" or aluminum) and ("TFT" or thin near film near transistor) and gate and gate near (insulat\$3 or dielectric) and (transparent\$3 or translucent\$3) near (conduct\$3) | USPAT | OR | ON | 2007/12/25 20:12 |

4/12/08 2:56:59 AM

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